Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial (PCT process)

2SC2859

Audio Frequency Low Power Amplifier Applications
Driver Stage Amplifier Applications
Switching Applications

• Excellent hFE linearity: hFE (2) = 25 (min) ($V_{CE} = 6 \text{ V}$, $I_{C} = 400 \text{ mA}$)

• Complementary to 2SA1182.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	35	V
Collector-emitter voltage	V _{CEO}	30	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	IC	500	mA
Base current	Ι _Β	50	mA
Collector power dissipation	PC	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

1. BASE 2. EMITTER S-MINI 3. COLLECTOR

SC-59

2-3F1A

Weight: 0.012 g (typ.)

JEITA

TOSHIBA

Electrical Characteristics (Ta = 25°C)

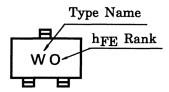
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 35 \text{ V}, I_{E} = 0$	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_		0.1	μА
DC current gain (Note) -	h _{FE (1)}	V _{CE} = 1 V, I _C = 100 mA	70		400	
	h _{FE (2)}	$V_{CE} = 6 \text{ V}, I_{C} = 400 \text{ mA}$	25			
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	0.1	0.25	٧
Base-emitter voltage	V _{BE}	V _{CE} = 1 V, I _C = 100 mA		0.8	1.0	V
Transition frequency	f _T	$V_{CE} = 6 \text{ V}, I_{C} = 20 \text{ mA}$	_	300	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 6 V, I _E = 0, f = 1 MHz	_	7	_	pF

Note: hFE (1) classification O (O): 70~140, Y (Y): 120~240, GR (G): 200~400

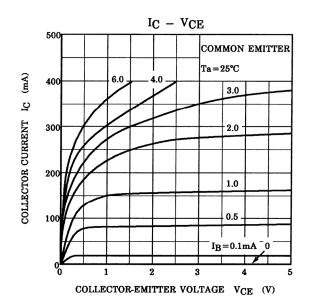
hFE (2) classification O: 25 min, Y: 40 min, GR: 70 min

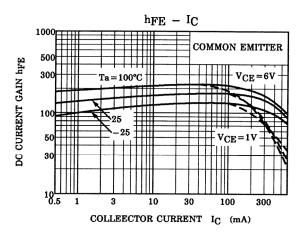
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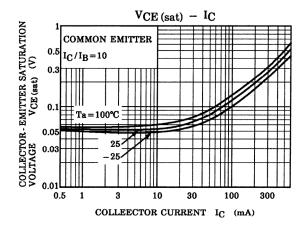
Marking

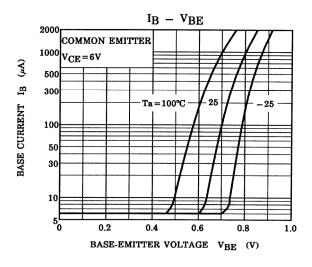


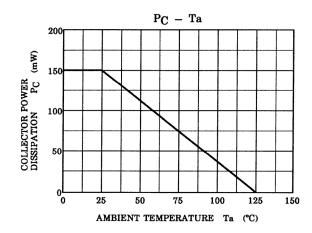
2007-11-01











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20070701-EN GENERAL

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